

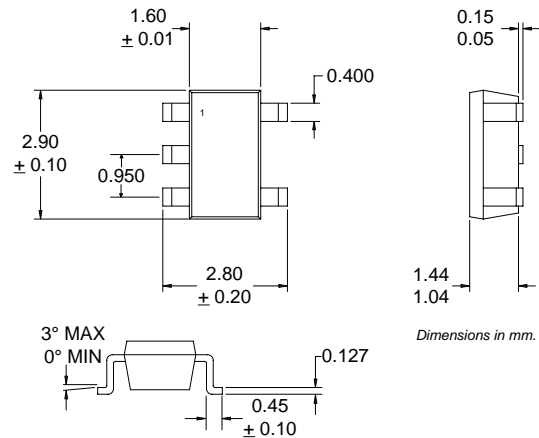
RoHS Compliant & Pb-Free Product

Typical Applications

- Broadband Gain Blocks
- Final PA for Low-Power Applications
- IF or RF Buffer Amplifiers
- Driver Stage for Power Amplifiers
- Oscillator Loop Amplifiers

Product Description

The RF2314 is a general purpose, low-cost, high performance amplifier designed for operation from a 2.7V to 6V supply with low current consumption. The circuit configuration with resistive feedback allows for broadband cascadable amplification. Feedback with capacitive compensation extends the bandwidth of the amplifier, and is designed for optimized noise figure. The device is unconditionally stable and internally matched to 50Ω. **No external components** are required. The RF2314 is available in a very small industry-standard SOT 5-lead surface mount package, enabling compact designs which conserve board space.

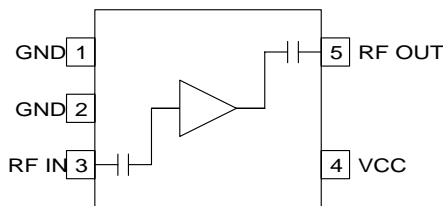


Optimum Technology Matching® Applied

- | | | |
|-------------------------------------|--|---------------------------------------|
| <input type="checkbox"/> Si BJT | <input checked="" type="checkbox"/> GaAs HBT | <input type="checkbox"/> GaAs MESFET |
| <input type="checkbox"/> Si Bi-CMOS | <input type="checkbox"/> SiGe HBT | <input type="checkbox"/> Si CMOS |
| <input type="checkbox"/> InGaP/HBT | <input type="checkbox"/> GaN HEMT | <input type="checkbox"/> SiGe Bi-CMOS |

Package Style: SOT 5-Lead

- Features
- 150MHz to 2500MHz Operation
 - 2.7V to 6.0V Single Supply
 - +18dBm Output IP₃ at 5V
 - 14dB Gain at 900MHz
 - 8.6dB Gain at 1900MHz
 - Low Current Consumption of 5mA at 3V



Functional Block Diagram

Ordering Information

RF2314	General Purpose Low Noise Amplifier
RF2314 PCBA	Fully Assembled Evaluation Board

RF Micro Devices, Inc. 7628 Thorndike Road Greensboro, NC 27409, USA	Tel (336) 664 1233 Fax (336) 664 0454 http://www.rfmd.com
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RF2314

Absolute Maximum Ratings

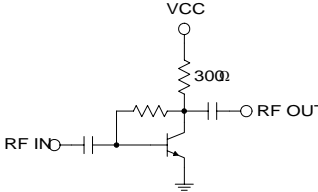
Parameter	Rating	Unit
Supply Voltage	8.0	V
Supply Current	32	mA
Storage Temperature	-40 to +150	°C



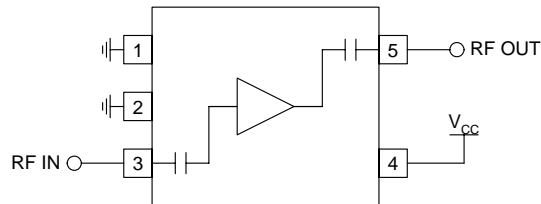
Caution! ESD sensitive device.

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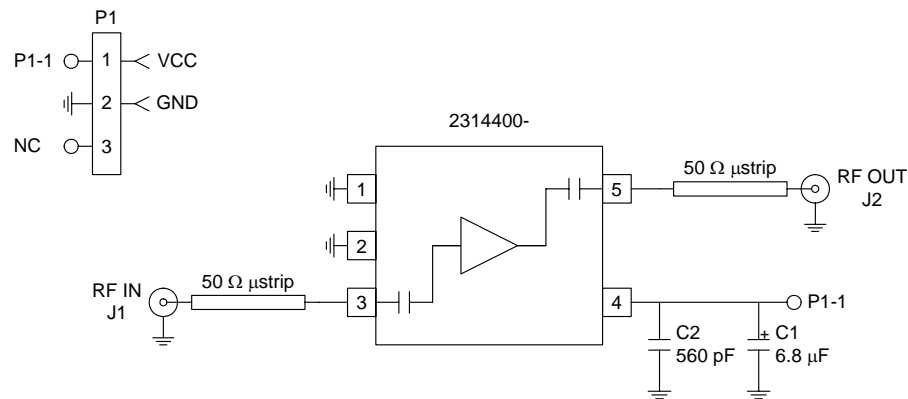
Parameter	Specification			Unit	Condition
	Min.	Typ.	Max.		
Operating Range					
Overall Frequency Range	150		2500	MHz	
Supply Voltage	2.7		6.0	V	
Operating Current (I_{CC})	2	5.7	9	mA	$V_{CC}=3V$, Temp= $27^{\circ}C$
	9	12.5	16	mA	$V_{CC}=5V$, Temp= $27^{\circ}C$
Operating Ambient Temperature	-40		+85	C	
3.0V Performance					
Gain		16.6		dB	Freq=150MHz, $V_{CC}=3V$, Temp= $27^{\circ}C$
Gain	11	12.9	14	dB	Freq=900MHz, $V_{CC}=3V$, Temp= $27^{\circ}C$
Noise Figure		1.4		dB	
OIP3	+3	+9		dBm	
OP1dB	-4	-1	+1	dBm	
Input Return Loss		10		dB	
Output Return Loss		17		dB	
Isolation		20		dB	
Gain	6.5	7.9	9	dB	Freq=1900MHz, $V_{CC}=3V$, Temp= $27^{\circ}C$
OIP3	+9	+12.5		dBm	
OP1dB	-2	-0.5	+1	dBm	
Gain	4	5.2	7	dB	Freq=2400MHz, $V_{CC}=3V$, Temp= $27^{\circ}C$
OIP3	+11	+15.3		dBm	
OP1dB	-1	+1.1	+3	dBm	
5.0V Performance					
Gain		19.1		dB	Freq=150MHz, $V_{CC}=5V$, Temp= $27^{\circ}C$
Gain	12	14.2	16	dB	Freq=900MHz, $V_{CC}=5V$, Temp= $27^{\circ}C$
Noise Figure		1.5		dB	
OIP3	+14	+18		dBm	
OP1dB	+3	+8	+11	dBm	
Input Return Loss		13		dB	
Output Return Loss		28		dB	
Isolation		20		dB	
Gain	6	8.2	10	dB	Freq=1900MHz, $V_{CC}=5V$, Temp= $27^{\circ}C$
OIP3	+18	+22		dBm	
OP1dB	+5	+6.7	+9	dBm	
Gain	3.5	5.1	7	dB	Freq=2400MHz, $V_{CC}=5V$, Temp= $27^{\circ}C$
OIP3	+19	+23		dB	
OP1dB	+6	+7.9	+10	dB	

Pin	Function	Description	Interface Schematic
1	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane.	
2	GND	Same as pin 1.	
3	RF IN	RF input pin. This pin is internally DC-blocked and thus does not require an external blocking capacitor. The input impedance of this pin is internally matched to 50Ω using resistive feedback.	
4	VCC	Supply connection. Generally, there is no need for an external bypass capacitor.	See pin 3 schematic.
5	RF OUT	RF output pin. The output impedance of this pin is internally matched to 50Ω using resistive feedback.	See pin 3 schematic.

Application Schematic

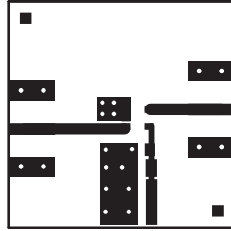
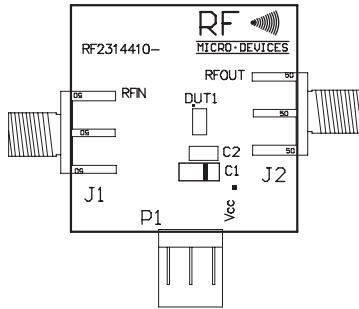


Evaluation Board Schematic (Download [Bill of Materials](http://www.rfmd.com) from www.rfmd.com.)

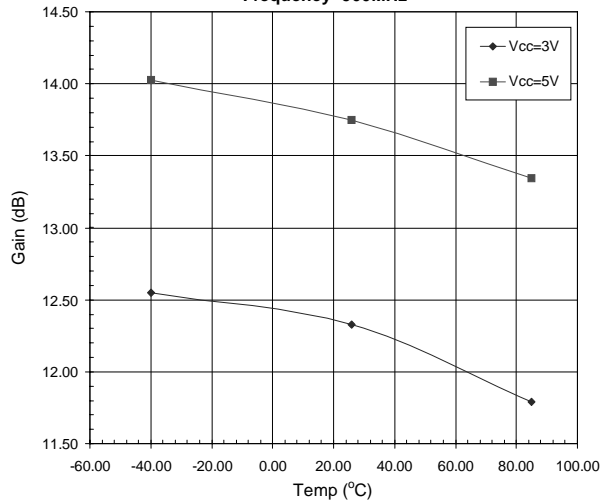


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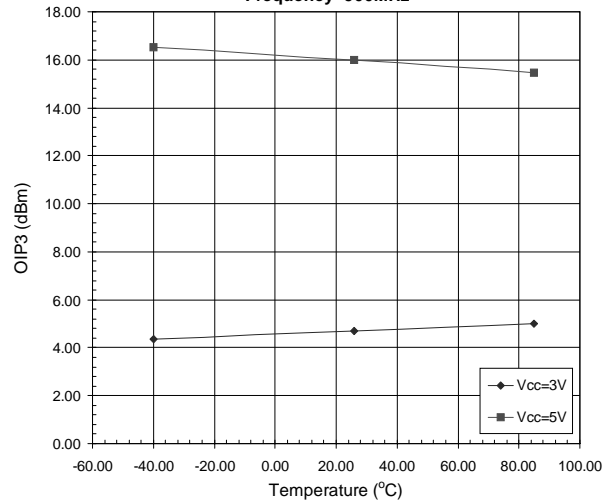
Evaluation Board Layout Board Size 1.0" x 1.0" Board Thickness 0.031", Board Material FR-4



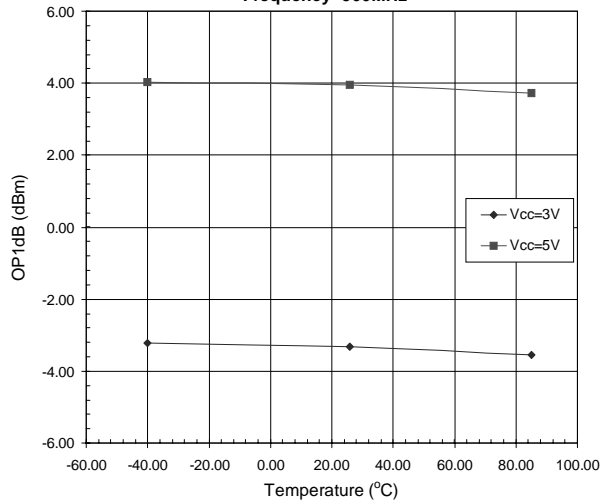
Gain versus Temperature
Frequency=900MHz



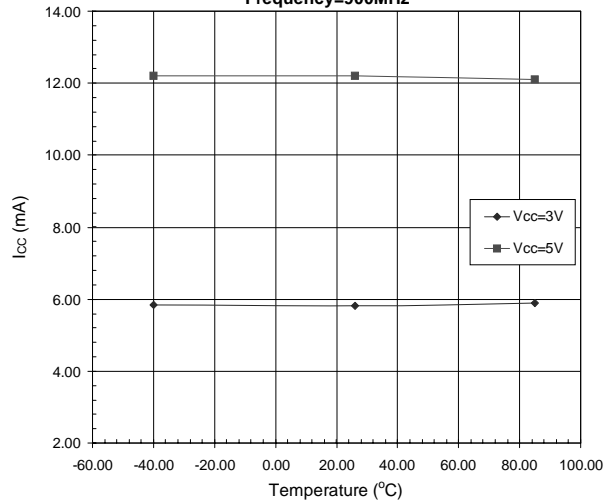
OIP3 versus Temperature
Frequency=900MHz



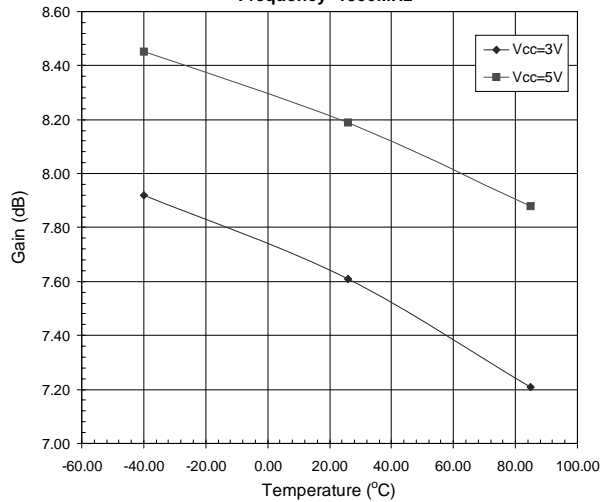
OP1dB versus Temperature
Frequency=900MHz



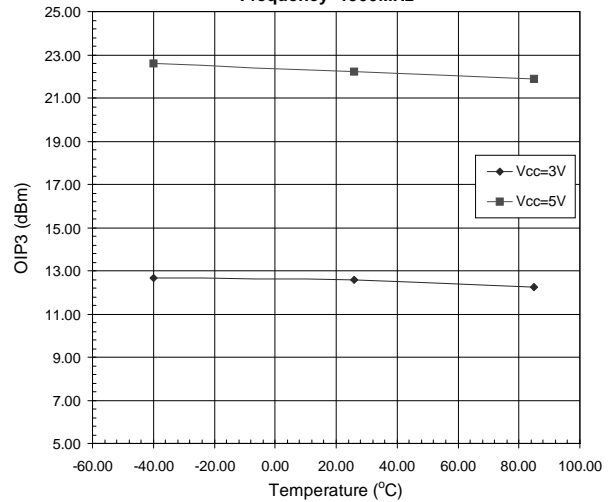
I_{CC} versus Temperature
Frequency=900MHz



Gain versus Temperature
Frequency=1900MHz

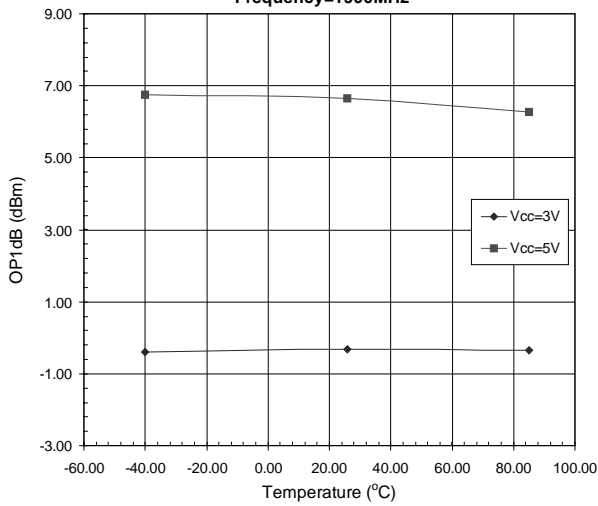


OIP3 versus Temperature
Frequency=1900MHz

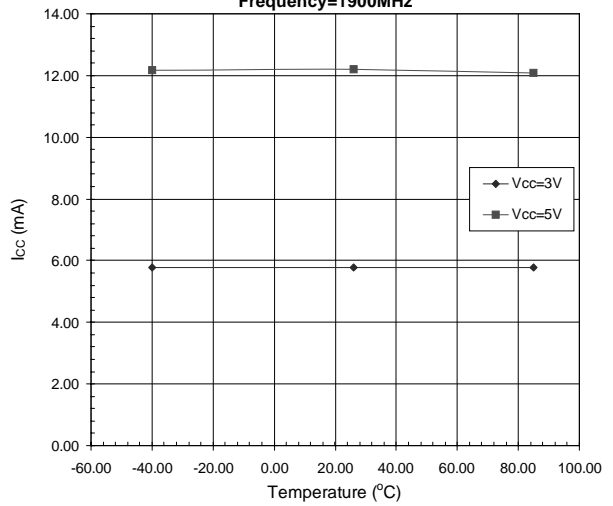


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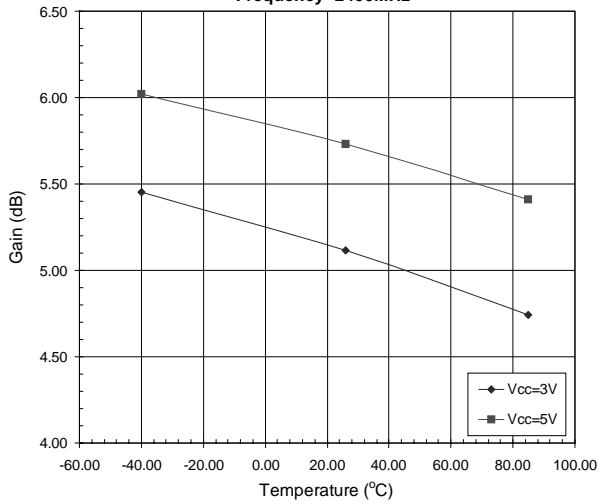
OP1dB versus Temperature
Frequency=1900MHz



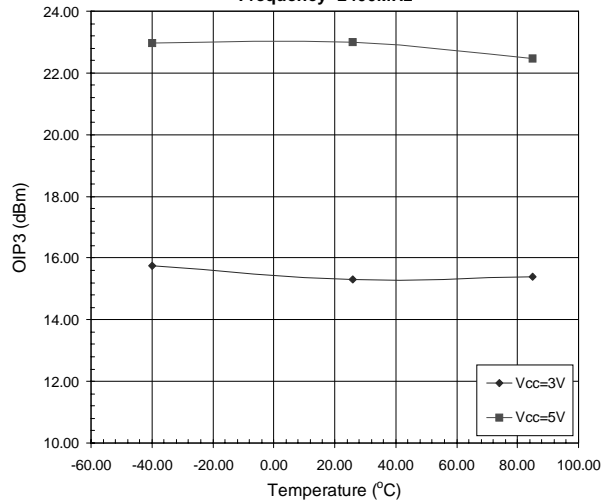
I_{cc} versus Temperature
Frequency=1900MHz



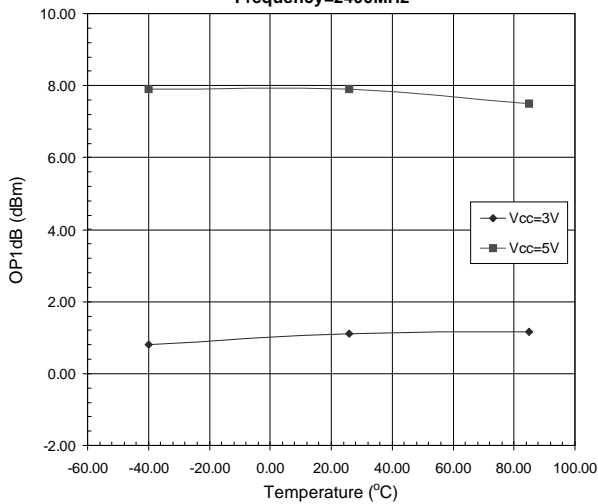
Gain versus Temperature
Frequency=2400MHz



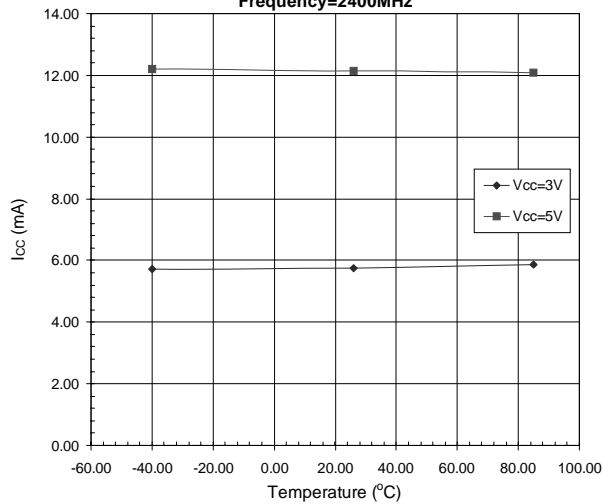
OIP3 versus Temperature
Frequency=2400MHz



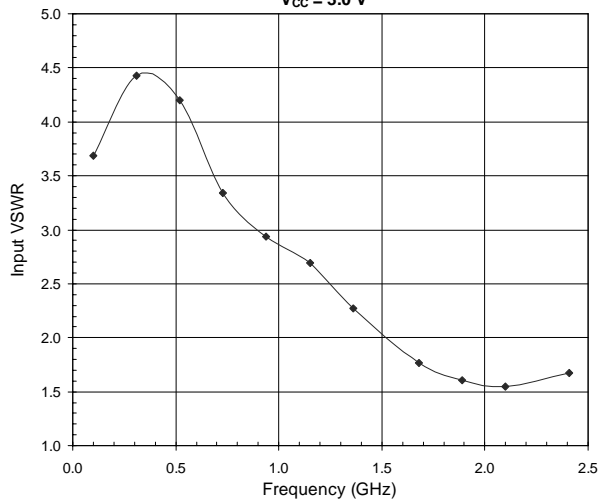
OP1dB versus Temperature
Frequency=2400MHz



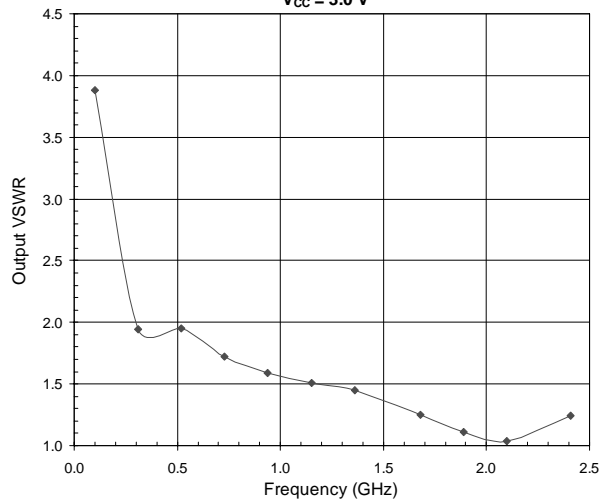
I_{cc} versus Temperature
Frequency=2400MHz



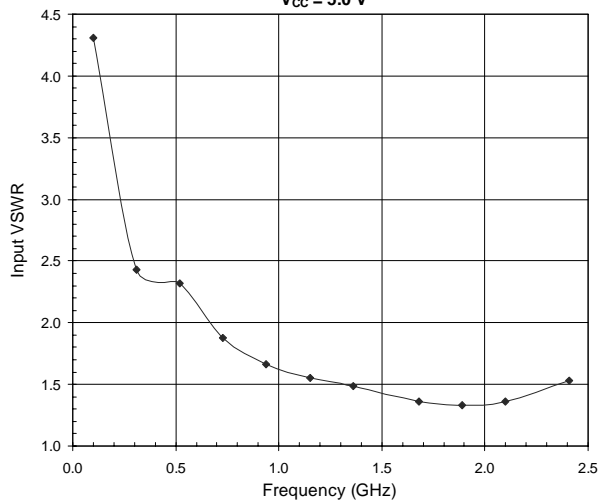
S11 of Evaluation Board versus Frequency
V_{CC} = 3.0 V



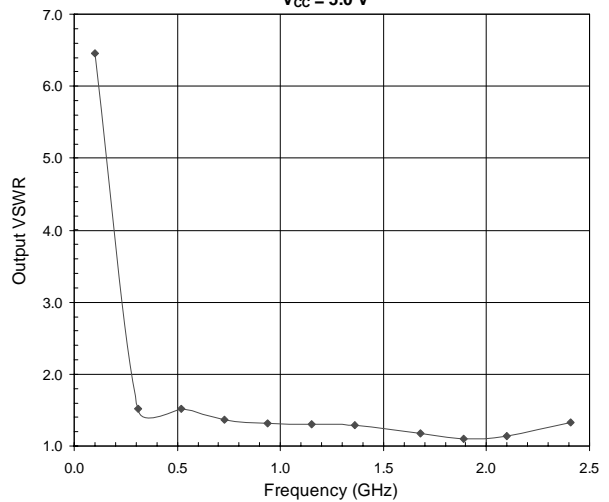
S22 of Evaluation Board versus Frequency
V_{CC} = 3.0 V



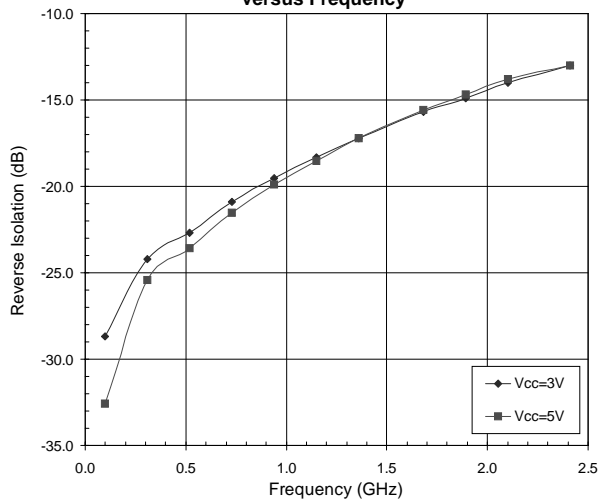
S11 of Evaluation Board versus Frequency
V_{CC} = 5.0 V



S22 of Evaluation Board versus Frequency
V_{CC} = 5.0 V

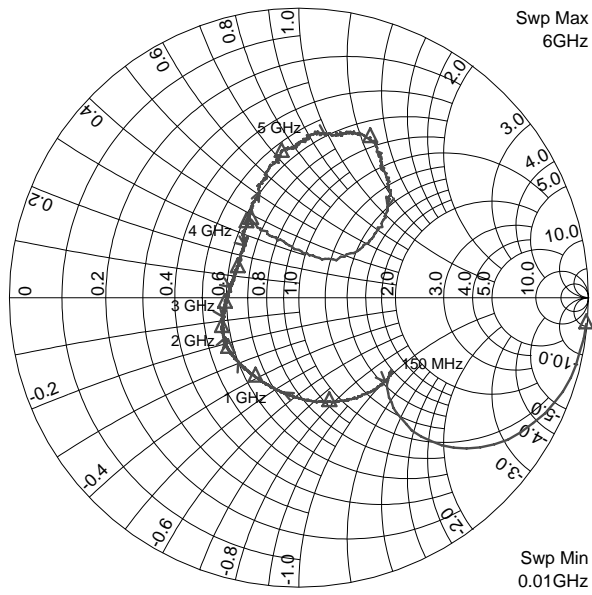


Reverse Isolation (S12) of Evaluation Board versus Frequency

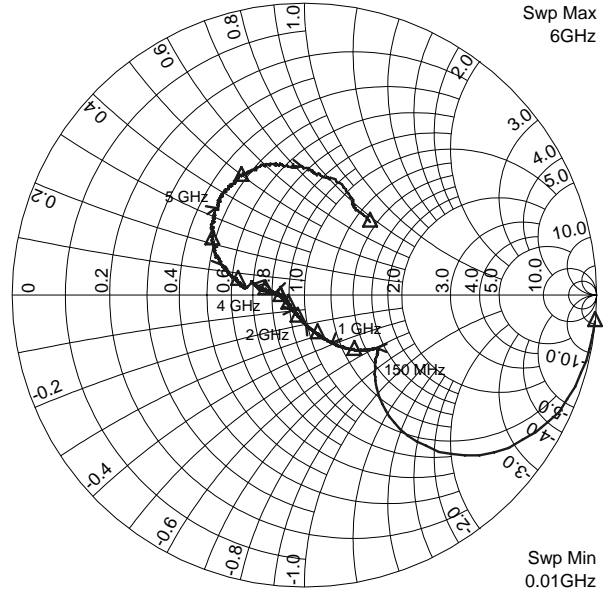


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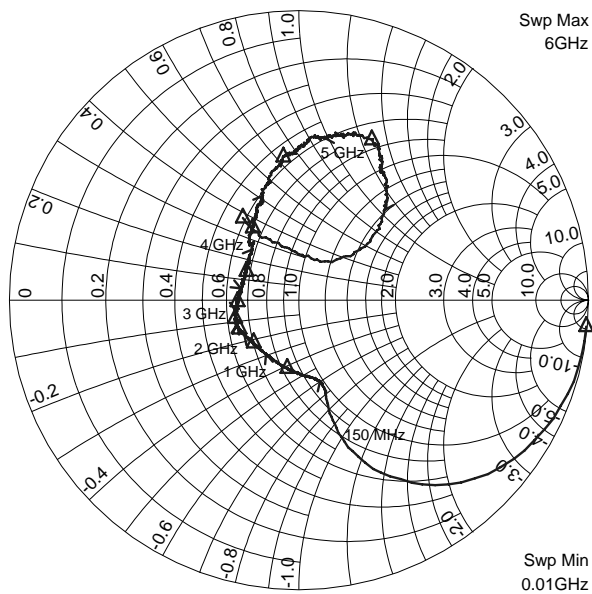
S11 Plot, $V_{CC} = 3V$



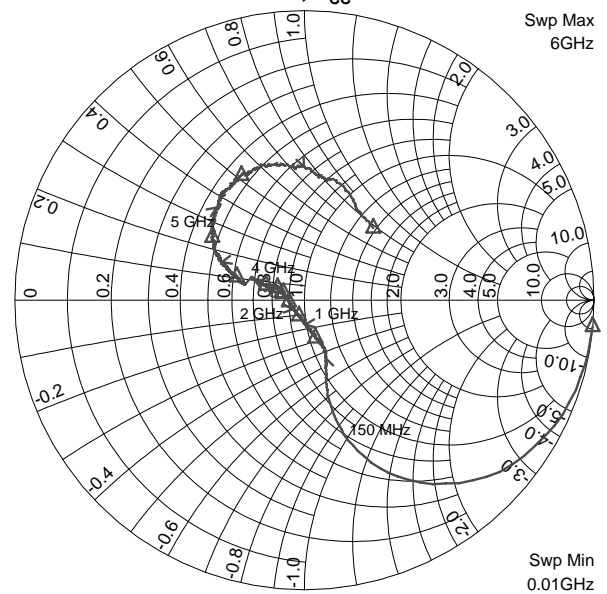
S22 Plot, $V_{CC} = 3V$



S11 Plot, $V_{CC} = 5V$



S22 Plot, $V_{CC} = 5V$



PCB Design Requirements

PCB Surface Finish

The PCB surface finish used for RFMD's qualification process is Electroless Nickel, immersion Gold. Typical thickness is 3μinch to 8μinch Gold over 180μinch Nickel.

PCB Land Pattern Recommendation

PCB land patterns are based on IPC-SM-782 standards when possible. The pad pattern shown has been developed and tested for optimized assembly at RFMD; however, it may require some modifications to address company specific assembly processes. The PCB land pattern has been developed to accommodate lead and package tolerances.

PCB Metal Land Pattern

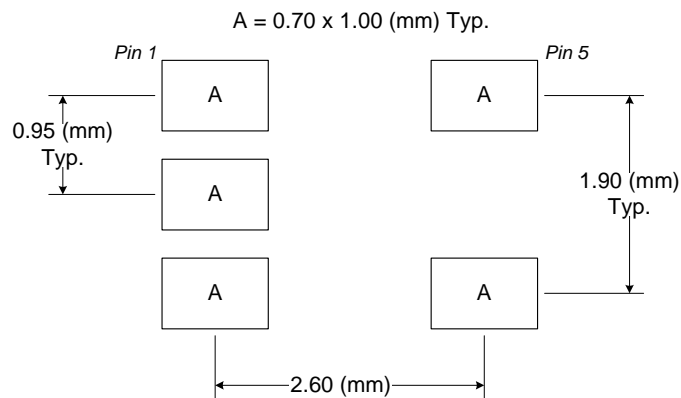


Figure 1. PCB Metal Land Pattern (Top View)

PCB Solder Mask Pattern

Liquid Photo-Imageable (LPI) solder mask is recommended. The solder mask footprint will match what is shown for the PCB metal land pattern with a 3mil expansion to accommodate solder mask registration clearance around all pads. The center-grounding pad shall also have a solder mask clearance. Expansion of the pads to create solder mask clearance can be provided in the master data or requested from the PCB fabrication supplier.

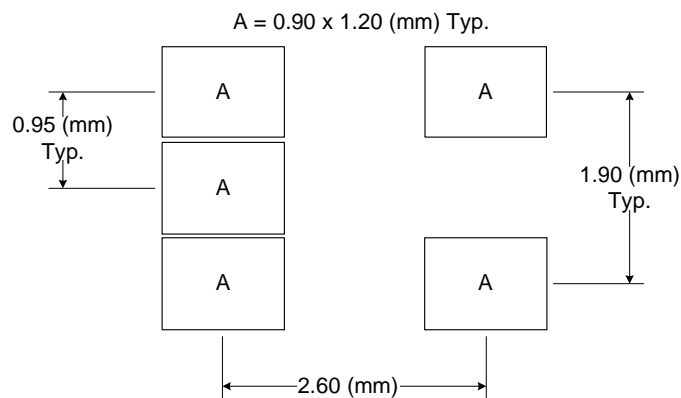


Figure 2. PCB Solder Mask Pattern (Top View)

Thermal Pad and Via Design

The PCB land pattern has been designed with a thermal pad that matches the exposed die paddle size on the bottom of the device.

Thermal vias are required in the PCB layout to effectively conduct heat away from the package. The via pattern shown has been designed to address thermal, power dissipation and electrical requirements of the device as well as accommodating routing strategies.

The via pattern used for the RFMD qualification is based on thru-hole vias between 0.203mm to 0.330mm finished hole size with 0.025mm plating on via walls. If micro vias are used in a design, it is suggested that the quantity of vias be increased by a 4:1 ratio to achieve similar results.

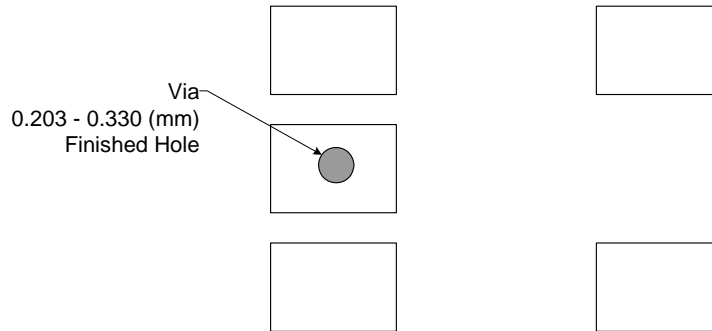


Figure 3. Thermal Pad and Via Design (RFMD qualification)